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National Semiconductor

LM2937-2.5, LM2937-3.3 400mA and 500mA Voltage Regulators General Description

The LM2937-2.5 and LM2937-3.3 are positive voltage regulators capable of supplying up to 500 mA of load current. Both regulators are ideal for converting a common 5V logic supply, or higher input supply voltage, to the lower 2.5V and 3.3V supplies to power VLSI ASIC's and microcontrollers. Special circuitry has been incorporated to minimize the quiescent current to typically only 10 mA with a full 500 mA load current when the input to output voltage differential is greater than 5V.

The LM2937 requires an output bypass capacitor for stability. As with most regulators utilizing a PNP pass transistor, the ESR of this capacitor remains a critical design parameter, but the LM2937-2.5 and LM2937-3.3 include special compensation circuitry that relaxes ESR requirements. The LM2937 is stable for all ESR ratings less than 5 Ω . This allows the use of low ESR chip capacitors.

The regulators are also suited for automotive applications, with built in protection from reverse battery connections,

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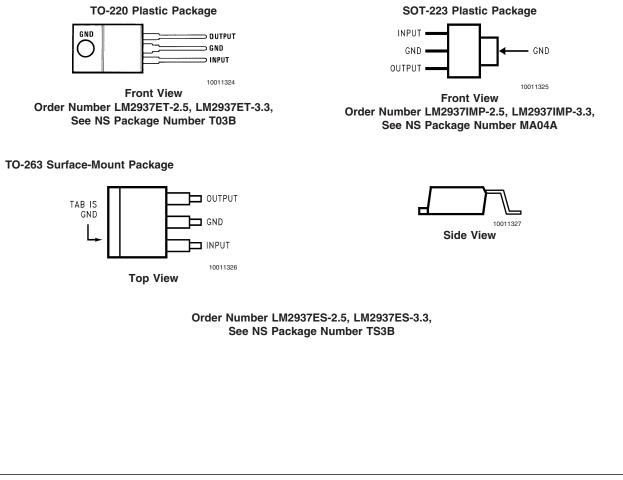
two-battery jumps and up to +60V/-50V load dump transients. Familiar regulator features such as short circuit and thermal shutdown protection are also built in.

Features

- Fully specified for operation over -40°C to +125°C
- Output current in excess of 500 mA (400mA for SOT-223 package)
- Output trimmed for 5% tolerance under all operating conditions
- Wide output capacitor ESR range, 0.01Ω up to 5Ω
- Internal short circuit and thermal overload protection
- Reverse battery protection
- 60V input transient protection
- Mirror image insertion protection



DS100113



LM2937-2.5, LM2937-3.3

Connection Diagrams and Ordering Information (Continued)

Temperature	Output Voltage		NSC	Package
Range	2.5	3.3	Package	
			Drawing	
$-40^{\circ}C \le T_A \le 125^{\circ}C$	LM2937ES-2.5	LM2937ES-3.3	TS3B	TO-263
	LM2937ET-2.5	LM2937ET-3.3	T03B	TO-220
$-40^{\circ}C \le T_A \le 85^{\circ}C$	LM2937IMP-2.5	LM2937IMP-3.3	MA04A	SOT-223
SOT-223 Package	L68B	L69B		
Markings				

The small physical size of the SOT-223 package does not allow sufficient space to provide the complete device part number. The actual devices will be labeled with the package markings shown.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Input Voltage	
Continuous	26V
Transient (t \leq 100 ms)	60V
Internal Power Dissipation (Note 2)	Internally Limited
Maximum Junction Temperature	150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature Soldering	
TO-220 (10 seconds)	260°C
TO-263 (10 seconds)	230°C

SOT-223 (Vapor Phase, 60 seconds) 215°C SOT-223 (Infrared, 15 seconds) 220°C ESD Susceptibility (Note 3)

Operating Conditions(Note 1)

Temperature Range (Note 2)	
LM2937ES, LM2937ET	$-40^{\circ}C \le T_A \le$
	125°C

LM2937IMP Input Voltage Range $-40^{\circ}C \le T_A \le 85^{\circ}C$ 4.75V to 26V

Electrical Characteristics(Note 4)

 $V_{IN} = V_{NOM} + 5V$, $I_{OUTmax} = 500$ mA for the TO-220 and TO-263 packages, $I_{OUTmax} = 400$ mA for the SOT-223 package, $C_{OUT} = 10 \ \mu$ F unless otherwise indicated. **Boldface limits apply over the entire operating temperature range, of the indicated device**, all other specifications are for $T_A = T_J = 25^{\circ}$ C.

Output Voltage (V _{OUT})		2.5V		3.3V		Units
Parameter	Conditions	Тур	Limit	Тур	Limit	1
Output Voltage	$5 \text{ mA} \leq I_{OUT} \leq I_{OUTmax}$		2.42		3.20	V (Min)
		2.5	2.38	3.3	3.14	V(Min)
			2.56		3.40	V(Max)
			2.62		3.46	V(Max)
Line Regulation(Note 5)	$4.75V \le V_{\rm IN} \le 26V,$	7.5	25	9.9	33	mV(Max)
	I _{OUT} = 5 mA					
Load Regulation	$5 \text{ mA} \leq I_{OUT} \leq I_{OUTmax}$	2.5	25	3.3	33	mV(Max)
Quiescent Current	$7V \le V_{IN} \le 26V,$	2	10	2	10	mA(Max)
	I _{OUT} = 5 mA					
	$V_{\rm IN} = (V_{\rm OUT} + 5V),$	10	20	10	20	mA(Max)
	$I_{OUT} = I_{OUTmax}$					
	$V_{IN} = 5V, I_{OUT} = I_{OUTmax}$	66	100 125	66	100 125	mA(Max)
Output Noise	10 Hz–100 kHz,	75		99		μVrms
Voltage	I _{OUT} = 5 mA					
Long Term Stability	1000 Hrs.	10		13.2		mV
Short-Circuit Current		1.0	0.6	1.0	0.6	A(Min)
Peak Line Transient	$t_{\rm f}$ < 100 ms, R _L = 100 Ω	75	60	75	60	V(Min)
Voltage						
Maximum Operational			26		26	V(Min)
Input Voltage						
Reverse DC	$V_{OUT} \ge -0.6V, R_L = 100\Omega$	-30	-15	-30	-15	V(Min)
Input Voltage						
Reverse Transient	$t_r < 1 \text{ ms}, \text{ R}_L = 100\Omega$	-75	-50	-75	-50	V(Min)
Input Voltage						

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Electrical specifications do not apply when operating the device outside of its rated Operating Conditions.

Note 2: The maximum allowable power dissipation at any ambient temperature is $P_{MAX} = (125 - T_A)/\theta_{JA}$, where 125 is the maximum junction temperature for operation, T_A is the ambient temperature, and θ_{JA} is the junction-to-ambient thermal resistance. If this dissipation is exceeded, the die temperature will rise above 125°C and the electrical specifications do not apply. If the die temperature rises above 150°C, the regulator will go into thermal shutdown. The junction-to-ambient thermal resistance θ_{JA} is 65°C/W, for the TO-220 package, 73°C/W for the TO-263 package, and 174°C/W for the SOT-223 package. When used with a heatsink, θ_{JA} is the sum of the device junction-to-case thermal resistance θ_{JC} of 3°C/W and the heatsink case-to-ambient thermal resistance. If the TO-263 or SOT-223 package (see Application Hints for more information on heatsinking).

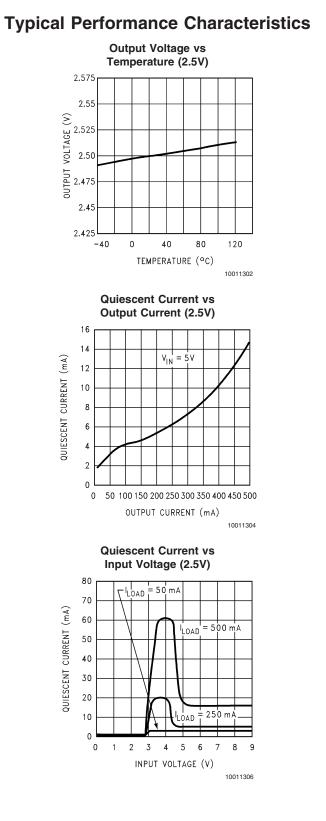
Note 3: ESD rating is based on the human body model, 100 pF discharged through 1.5 k Ω .

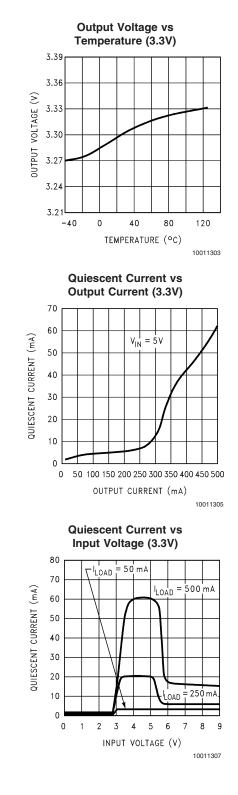
Note 4: Typicals are at $T_J = 25^{\circ}C$ and represent the most likely parametric norm.

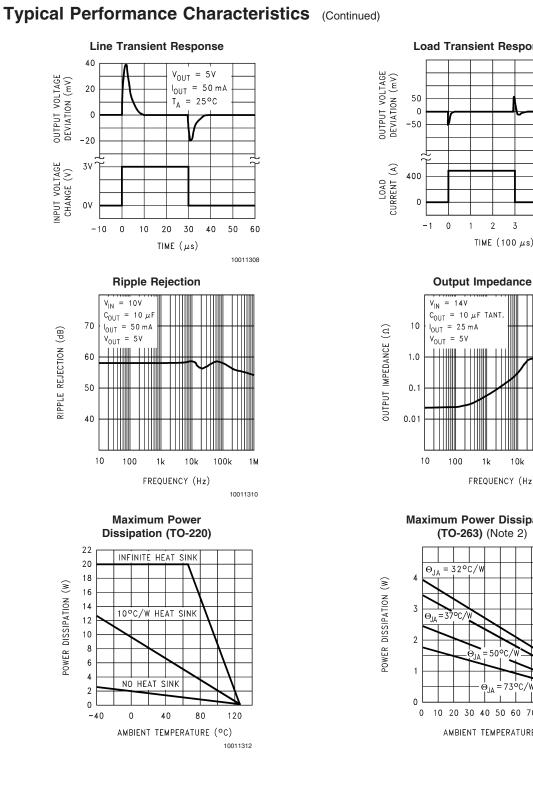
2 kV

Electrical Characteristics(Note 4) (Continued)

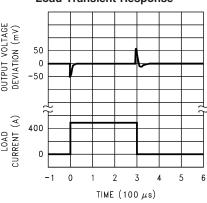
Note 5: The minimum input voltage required for proper biasing of these regulators is 4.75V. Below this level the outputs will fall out of regulation. This effect is not the normal dropout characteristic where the output falls out of regulation due to the PNP pass transistor entering saturation. If a value for worst case effective input to output dropout voltage is required in a specification, the values should be 2.37V maximum for the LM2937-2.5 and 1.6V maximum for the LM2937-3.3.



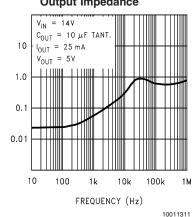




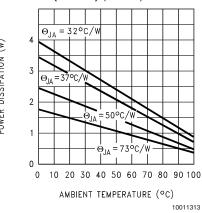
Load Transient Response



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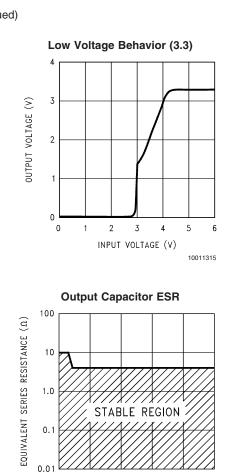


Maximum Power Dissipation



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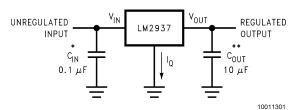
Typical Performance Characteristics (Continued) Low Voltage Behavior (2.5V) 4 OUTPUT VOLTAGE (V) 3 2 1 0 0 3 4 1 2 5 6 INPUT VOLTAGE (V) 10011314 Output at Voltage Extremes 4 3.3V 3 OUTPUT VOLTAGE (V) 2.5V 2 0 - 1 -30 -20 -10 0 10 20 40 30 INPUT VOLTAGE (V) 10011316 **Peak Output Current** 1.5 VIN = 14V OUTPUT CURRENT (A) 1.0 0.5 0 -40 0 40 80 120 TEMPERATURE (°C) 10011318



100 200 300 400 500 OUTPUT CURRENT 10011317

0

Typical Application



* Required if the regulator is located more than 3 inches from the power supply filter capacitors.

** Required for stability. C_{out} must be at least 10 μ F (over the full expected operating temperature range) and located as close as possible to the regulator. The equivalent series resistance, ESR, of this capacitor may be as high as 3Ω .

Application Hints

EXTERNAL CAPACITORS

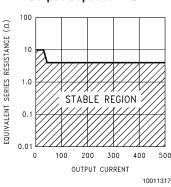
The output capacitor is critical to maintaining regulator stability, and must meet the required conditions for both ESR (Equivalent Series Resistance) and minimum amount of capacitance.

MINIMUM CAPACITANCE:

The minimum output capacitance required to maintain stability is 10 μF (this value may be increased without limit). Larger values of output capacitance will give improved transient response.

ESR LIMITS:

The ESR of the output capacitor will cause loop instability if it is too high or too low. The acceptable range of ESR plotted versus load current is shown in the graph below. *It is essential that the output capacitor meet these requirements, or oscillations can result.*



Output Capacitor ESR

FIGURE 1. ESR Limits

It is important to note that for most capacitors, ESR is specified only at room temperature. However, the designer must ensure that the ESR will stay inside the limits shown over the entire operating temperature range for the design.

For aluminum electrolytic capacitors, ESR will increase by about 30X as the temperature is reduced from 25° C to -40° C. This type of capacitor is not well-suited for low temperature operation.

Solid tantalum capacitors have a more stable ESR over temperature, but are more expensive than aluminum electrolytics. A cost-effective approach sometimes used is to parallel an aluminum electrolytic with a solid Tantalum, with the total capacitance split about 75/25% with the Aluminum being the larger value.

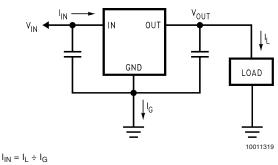
If two capacitors are paralleled, the effective ESR is the parallel of the two individual values. The "flatter" ESR of the Tantalum will keep the effective ESR from rising as quickly at low temperatures.

HEATSINKING

A heatsink may be required depending on the maximum power dissipation and maximum ambient temperature of the application. Under all possible operating conditions, the junction temperature must be within the range specified under Absolute Maximum Ratings.

To determine if a heatsink is required, the power dissipated by the regulator, P_D , must be calculated.

The figure below shows the voltages and currents which are present in the circuit, as well as the formula for calculating the power dissipated in the regulator:



 $\mathsf{P}_\mathsf{D} = (\mathsf{V}_\mathsf{IN} - \mathsf{V}_\mathsf{OUT}) \ \mathsf{I}_\mathsf{L} + (\mathsf{V}_\mathsf{IN}) \ \mathsf{I}_\mathsf{G}$

FIGURE 2. Power Dissipation Diagram

The next parameter which must be calculated is the maximum allowable temperature rise, $T_{\rm R}$ (max). This is calculated by using the formula:

$$T_{R}$$
 (max) = T_{J} (max) - T_{A} (max)

- where: T_J (max) is the maximum allowable junction temperature, which is 125°C for commercial grade parts.
 - T_A (max) is the maximum ambient temperature which will be encountered in the application.

Using the calculated values for $T_R(max)$ and P_D , the maximum allowable value for the junction-to-ambient thermal resistance, $\theta_{(J-A)}$, can now be found:

$$\theta_{(J-A)} = T_R (max)/P_D$$

IMPORTANT: If the maximum allowable value for $\theta_{(J-A)}$ is found to be $\geq 53^{\circ}$ C/W for the TO-220 package, $\geq 80^{\circ}$ C/W for the TO-263 package, or $\geq 174^{\circ}$ C/W for the SOT-223 package, no heatsink is needed since the package alone will dissipate enough heat to satisfy these requirements.

If the calculated value for $\theta_{(\mathsf{J}-\mathsf{A})} \text{falls}$ below these limits, a heatsink is required.

HEATSINKING TO-220 PACKAGE PARTS

The TO-220 can be attached to a typical heatsink, or secured to a copper plane on a PC board. If a copper plane is to be used, the values of $\theta_{(J-A)}$ will be the same as shown in the next section for the TO-263.

If a manufactured heatsink is to be selected, the value of heatsink-to-ambient thermal resistance, $\theta_{(\text{H}-\text{A})},$ must first be calculated:

$$\theta_{(H-A)} = \theta_{(J-A)} - \theta_{(C-H)} - \theta_{(J-C)}$$

- Where: $\theta_{(J-C)}$ is defined as the thermal resistance from the junction to the surface of the case. A value of 3°C/W can be assumed for $\theta_{(J-C)}$ for this calculation.
 - $\begin{array}{l} \theta_{(\text{C}-\text{H})} & \text{is defined as the thermal resistance between} \\ \text{the case and the surface of the heatsink. The} \\ \text{value of } \theta_{(\text{C}-\text{H})} \text{ will vary from about } 1.5^{\circ}\text{C/W} \text{ to} \\ \text{about } 2.5^{\circ}\text{C/W} \text{ (depending on method of attachment, insulator, etc.). If the exact value is} \\ \text{unknown, } 2^{\circ}\text{C/W} \text{ should be assumed for} \\ \theta_{(\text{C}-\text{H})}. \end{array}$

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1 2 3 COPPER FOIL AREA (SQ. IN.)

10011322

FIGURE 5. $\theta_{(J-A)}$ vs Copper (2 ounce) Area for the SOT-223 Package

Figure 5 and Figure 6 show the information for the SOT-223 package. Figure 6 assumes a $\theta_{(J-A)}$ of 74°C/W for 1 ounce

copper and 51°C/W for 2 ounce copper and a maximum

junction temperature of +85°C.

≥200 200

170

140

110

80

50

0

THERMAL RESISTANCE $\theta(J-A)$ IN

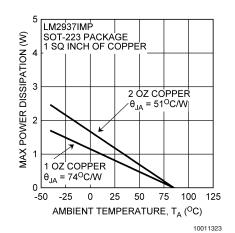


FIGURE 6. Maximum Power Dissipation vs T_{AMB} for the SOT-223 Package

Please see AN1028 for power enhancement techniques to be used with the SOT-223 package.

SOT-223 SOLDERING RECOMMENDATIONS

It is not recommended to use hand soldering or wave soldering to attach the small SOT-223 package to a printed circuit board. The excessive temperatures involved may cause package cracking.

Either vapor phase or infrared reflow techniques are preferred soldering attachment methods for the SOT-223 package.

Application Hints (Continued)

When a value for $\theta_{(H-A)}$ is found using the equation shown, a heatsink must be selected that has a value that is less than or equal to this number.

 $\theta_{(\text{H}-\text{A})}$ is specified numerically by the heatsink manufacturer in the catalog, or shown in a curve that plots temperature rise vs power dissipation for the heatsink.

HEATSINKING TO-263 AND SOT-223 PACKAGE PARTS

Both the TO-263 ("S") and SOT-223 ("MP") packages use a copper plane on the PCB and the PCB itself as a heatsink. To optimize the heat sinking ability of the plane and PCB, solder the tab of the package to the plane.

Figure 3 shows for the TO-263 the measured values of $\theta_{(J-A)}$ for different copper area sizes using a typical PCB with 1 ounce copper and no solder mask over the copper area used for heatsinking.

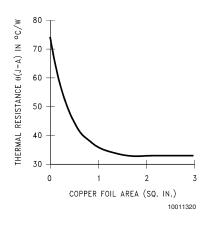


FIGURE 3. $\theta_{(J-A)}$ vs Copper (1 ounce) Area for the TO-263 Package

As shown in the figure, increasing the copper area beyond 1 square inch produces very little improvement. It should also be observed that the minimum value of $\theta_{(J-A)}$ for the TO-263 package mounted to a PCB is 32°C/W.

As a design aid, *Figure 4* shows the maximum allowable power dissipation compared to ambient temperature for the TO-263 device (assuming $\theta_{(J-A)}$ is 35°C/W and the maximum junction temperature is 125°C).

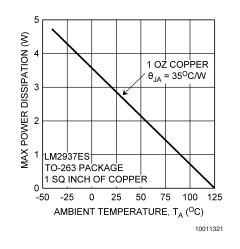


FIGURE 4. Maximum Power Dissipation vs $\rm T_{AMB}$ for the TO-263 Package

